

Code No: RT31041

R13

SET - 1

III B. Tech I Semester Regular/Supplementary Examinations, October/November- 2017
PULSE AND DIGITAL CIRCUITS

(Common to Electronics and Communication Engineering and Electronics and Instrumentation Engineering)

Time: 3 hours

Max. Marks: 70

- Note: 1. Question Paper consists of two parts (**Part-A** and **Part-B**)
2. Answering the question in **Part-A** is compulsory
3. Answer any **THREE** Questions from **Part-B**

PART -A

- 1 a) Determine the upper 3-dB frequency for low pass RC circuit, if a pulse of $0.5\mu\text{sec}$ is required to pass without distortion. Find the value of resistance if the capacitor is $0.001\mu\text{F}$. [4M]
- b) Draw the diode based negative clipper and draw its waveforms [3M]
- c) Give the Comparison of various logic families [4M]
- d) Draw and explain the fixed bias transistor bistable multivibrator [3M]
- e) Draw the constant current sweep circuit and explain [4M]
- f) Explain the principle of synchronization with frequency division [4M]

PART -B

- 2 a) Explain clearly with the help of a circuit and waveforms the response of high pass RC circuit for step and pulse input [8M]
- b) Explain (i) the working of attenuator as a CRO Probe ii) Ringing circuit [8M]
- 3 a) Compare and contrast series diode clipper and shunt diode clipper [8M]
- b) In a shunt clipper circuit $v_m = 20 \sin \omega t$, $R = 1\text{K}\Omega$, and $V_R = 10\text{V}$ is obtained from a potential divider circuit using 100 V supply and 10 K Ω potential divider. [8M]
 - i) Draw the circuit
 - ii) If $R_f = 50 \Omega$ and $R_r = \infty$ and $V_\gamma = 0$, Sketch the input and output waveforms.
- 4 a) Explain how transistor acts as a switch? Draw the base and collector waveforms by indicating all the time intervals. [8M]
- b) Realize a two-input NAND gate using diode transistor logic and explain its operation with the help of truth table. [8M]
- 5 a) Design a collector-coupled monostable multivibrator using an n-p-n silicon transistor with $h_{FE(\min)} = 40$, $V_{BE(\text{cut off})} \approx 0 \text{ V}$ and $I_{B(\text{sat})} = 1.5I_{B(\min)}$. Given that: $V_{CC} = 10 \text{ V}$, $I_{C(\text{sat})} = 5 \text{ mA}$, $R_{C1} = R_{C2} = R_C$, $V_{CE(\text{sat})} = 0.2 \text{ V}$ and $V_{BE(\text{sat})} = 0.7 \text{ V}$. If the pulse width required is 1 ms, calculate the value of C. [8M]
- b) Derive expression for the pulse width of a monostable multivibrator [8M]

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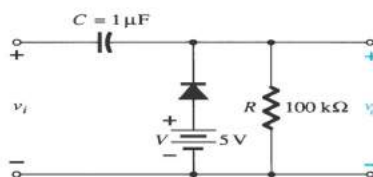
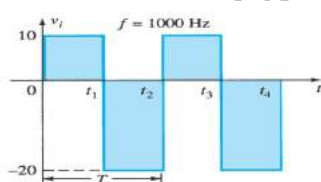
3. Answer any **THREE** Questions from **Part-B**

PART -A

- 1 a) For a high pass RC circuit it is desired to pass a 5 m sec sweep for a ramp input, with less than 0.5% transmission error. Determine the highest possible value of the lower 3-dB frequency. [3M]
- b) Draw the diode based positive clipper and draw its waveforms [4M]
- c) Present the piecewise linear characteristics of a diode [3M]
- d) Explain about commutating capacitors in bistable multi vibrator [4M]
- e) Compare voltage and current time base generators [4M]
- f) Define phase delay and phase jitter [4M]

PART -B

- 2 a) Explain the working of a piece-wise linear model of diode. [8M]
- b) A two input NAND gate has $V_{cc}=+5V$ and $1 K\Omega$ load connected to its output? Calculate the output voltage i) When both input are Low ii) when both input are High. [8M]
- 3 a) Draw the emitter coupled clipper, explain its operation and discuss its transfer characteristics. [8M]
- b) Determine v_o for the following circuit with the input shown and draw the output waveform (consider ideal diode). [8M]



- 4 a) Derive an expression for collector-to-emitter breakdown voltage, with open circuited base, BV_{CEO} in terms of collector-to-base breakdown voltage, with open circuited emitter, BV_{CBO} [8M]
- b) Realize a three-input NAND gate using transistor transistor logic and explain its operation with the help of truth table. [8M]

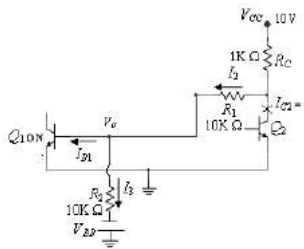
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- 5 a) For a collector-coupled monostable multivibrator circuit shown in Figure , [8M]
 $R_1 = R_2 = R = 10 \text{ k}\Omega$, $C = 0.01 \text{ }\mu\text{F}$, $R_C = 1 \text{ k}\Omega$, $V_{CC} = 10 \text{ V}$, $h_{FE} = 20$. In the quasi-stable state, Q_1 is in the active region with collector current of 2 mA. Find the time period and the value of V_{BB} . Neglect junction voltages.

$$I_{B(\text{sat})} = 1.5 I_{B(\text{min})}$$



- b) Discuss the design of fixed bias bistable multivibrator. [8M]
- 6 a) With suitable diagram, explain the function of sweep circuit using UJT. [8M]
 b) With neat circuit, explain about transistor miller time base generator. [8M]
- 7 a) Draw and explain with relevant waveforms the process of frequency division by an Astable multivibrator [8M]
 b) Explain the function of a sampling gate used in Sampling Scopes also explain how sampling gate is used in chopping amplifiers. [8M]

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PART -A

- 1 a) For a low pass RC circuit it is desired to pass a 3 msec sweep for a ramp input, with less than 0.5% transmission error. Determine the highest possible value of the upper 3-dB frequency. [4M]
- b) Draw the diode based positive clamper and draw relevant waveforms [4M]
- c) Give the comparison between TTL and CMOS families [3M]
- d) Compare all the three multivibrators with corresponding circuits [4M]
- e) Why the time base generators are called as sweep circuits? [3M]
- f) Draw and explain the operating principle of bidirectional sampling gates [4M]

PART -B

- 2 a) A symmetrical square wave of peak to peak amplitude V Volts and frequency f Hz is applied to a high pass RC circuit, show that the percentage tilt is given by $P = \frac{1 - e^{-1/2 fRC}}{1 + e^{-1/2 fRC}} \times 200\%$ [8M]
- b) Analyze the low pass RC circuit for the exponential input with help of waveforms. [8M]
- 3 a) Design a diode clamper to restore a dc level of +3 Volts to an input signal of peak to peak value 12 Volts. Assume the drop across diode as 0.7 Volts. [8M]
- b) Discuss in detail the effects of diode characteristics on clamping voltage. [8M]
- 4 a) Explain the saturation parameters of transistor and their variation with temperature [8M]
- b) A silicon transistor has $h_{FE}=50$, $I_{CO}=0.1\mu A$, the cut-in voltage $V_{\gamma}=0.6V$. The parameter 'n' of avalanche multiplication is 4 and $BV_{CBO}=40V$. [8M]
 - i) Find BV_{CEO}
 - ii) Find BV_{CER} if $R_B=1M\Omega$
 - iii) Find BV_{CEX} , assume $V_{BB}=20V$ and $R_B=10K\Omega$
- 5 a) Design a symmetric collector-coupled astable multivibrator to generate a square wave of 10 kHz having peak-to-peak amplitude of 10 V where, $h_{FEmin}=30$, $V_{CE(sat)}=0.2V$, $I_{C(sat)}=2mA$. [8M]
- b) Prove that an astable multivibrator works as voltage to frequency converter [8M]

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- 6 a) How can represent deviation from linearity in sweep circuits? Derive the relationamong possible errors in sweep circuits. [8M]
- b) The specifications of UJT are given as $\eta = 0.6$, $V_V = 2 \text{ V}$, $R_{BB} = 5 \text{ k}\Omega$, $I_V = 1.5 \text{ mA}$, $I_P = 8 \text{ }\mu\text{A}$ and $V_{BB} = 18 \text{ V}$. Calculate the component values of the UJT sweep circuit to generate an output sweep frequency of 10 kHz with sweep amplitude of 12 V. [8M]
- 7 a) Explain Synchronization of a sweep circuit with symmetrical signals [8M]
- b) Compare unidirectional and bidirectional sampling gates [8M]

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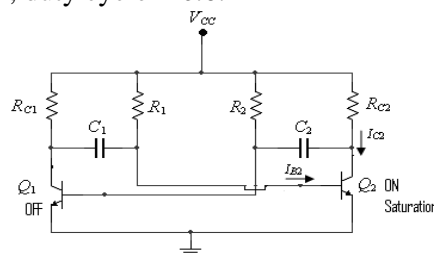
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PART -A

- 1 a) Show that the low pass RC circuit acts as an integrator [3M]
- b) Draw the diode based negative clamper and draw relevant waveforms [4M]
- c) Draw and explain the basic CMOS inverter circuit [3M]
- d) Draw the Schmitt trigger circuit and discuss its operation [4M]
- e) What are different methods of generating time base waveform [4M]
- f) Compare sampling gates with logic gates [4M]

PART -B

- 2 a) A 2 KHz symmetric square wave of ± 20 V is applied to a RC circuit having 2 msec. time constant. Calculate and plot the output to the scale for RC configuration as. i) High pass circuit ii) Low pass circuit. [8M]
- b) Draw explain the RLC circuit that can generate nearly undamped oscillations and explain its working. [8M]
- 3 a) Draw the diode differentiator comparator and discuss its working with the help of ramp input signal [8M]
- b) State and prove clamping circuit theorem. [8M]
- 4 a) With neat sketches and necessary equations, explain in detail about transistor switching times [8M]
- b) Realize NAND and NOR gates using CMOS logic and explain their operation with the help of truth table. [8M]
- 5 a) Design an unsymmetrical astable multivibrator shown in Figure, using silicon n- p-n transistors having an output amplitude of 12 V. Given, $I_{C(sat)} = 5$ mA, $h_{FEmin} = 50$, $f = 5$ kHz, duty cycle = 0.6. [8M]



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- b) Calculate the component values of a monostable multivibrator using silicon *npn* transistors generating an output pulse of 150 μsec . duration. Given (h_{fe})_{min}=30, $I_C(\text{sat})=6\text{mA}$, $V_{CC}=6\text{V}$ and $V_{BB}= -1.5\text{V}$. If $r'_{bb}=100\Omega$, find the magnitude of the overshoot. [8M]
- 6 a) Draw and explain the transistorized constant current sweep generator circuit. Derive expression for slope error and sweep voltage. [8M]
- b) How a compensation circuit improves the linearity of a Bootstrap voltage time base generator? Discuss. [8M]
- 7 a) What is synchronization? Why it is necessary in waveform generators? Explain the synchronization of a sweep circuit with symmetrical signals. [8M]
- b) Write an account of bidirectional diode based sampling gates [8M]

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